

PC817 Series

High Density Mounting Type Photocoupler

※ Lead forming type (I type) and taping reel type (P type) are also available. (PC8171/PC817P) (Page 656)
 ※ TUV (VDE0884) approved type is also available as an option.

■ Features

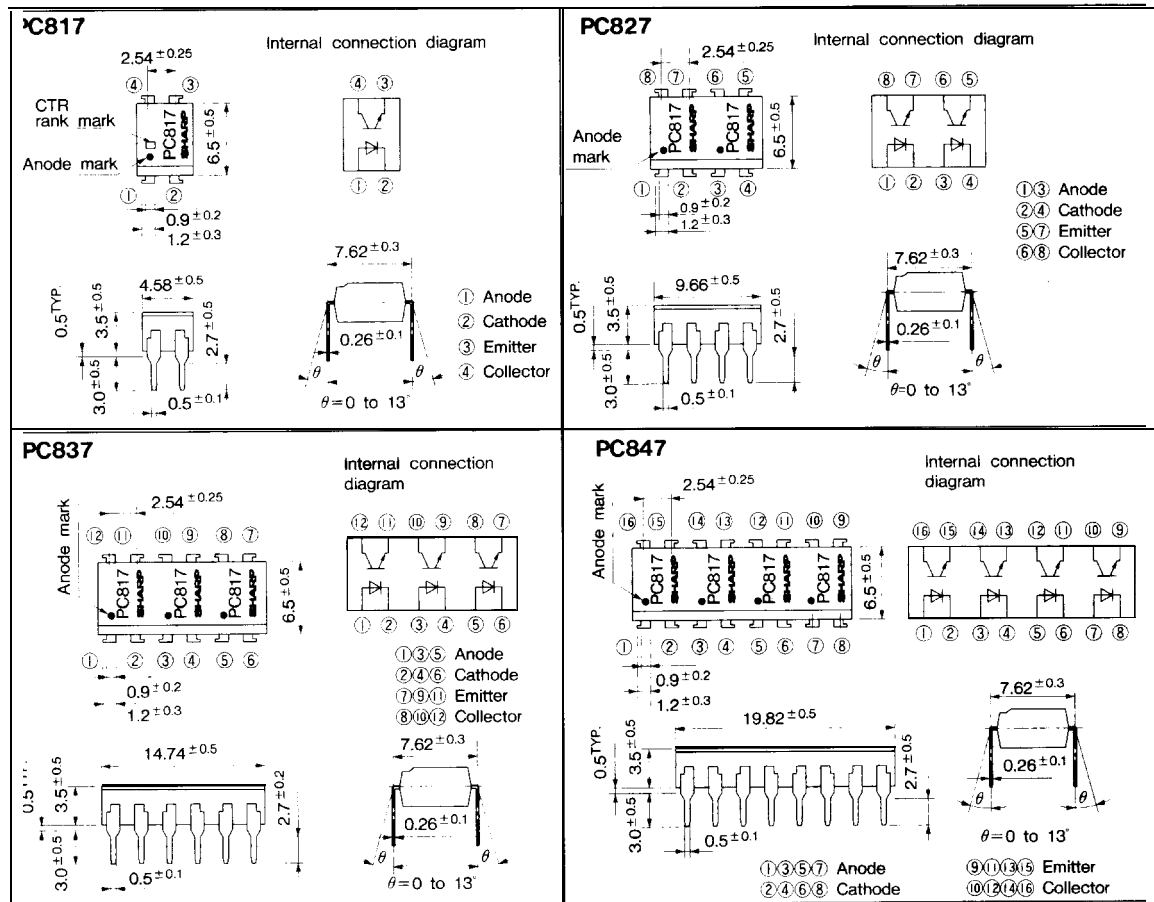
1. Current transfer ratio
 (CTR : MIN. 50% at $I_t = 5\text{mA}$)
2. High isolation voltage between input and output ($V_{iso} : 5,000V_{rms}$)
3. Compact dual-in-line package
 PC817 : 1-channel type
 PC827 : 2-channel type
PC837 : 3-channel type
 PC847 : 4-channel type
4. Recognized by UL, file No. E64380

■ Applications

1. Computer terminals
2. System appliances, measuring instruments
3. Registers, copiers, automatic vending machines
4. Electric home appliances, such as fan heaters, etc.
5. Medical instruments, physical and chemical equipment
6. Signal transmission between circuits of different potentials and impedances

■ Outline Dimensions

(Unit : mm)



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Photocouplers

■ Absolute Maximum Ratings

(Ta = 25℃)

Parameter		Symbol	Rating	Unit
Input	Forward current	IF	50	mA
	*1 Peak forward current	IFM	1	A
	Reverse voltage	VR	6	V
	Power dissipation	P	70	mW
output	Collector -emitter voltage	VCEO	35	v
	Emitter -collector voltage	VECO	6	V
	Collector current	IC	50	mA
	Collector power dissipation	PC	150	mW
Total power dissipation		Ptot	200	mW
*2 Isolation voltage		Viso	5000	Vrms
Operating temperature		Tj, op	-30 to +100	℃
Storage temperature		Tstg	-55 to +125	℃
*3 Soldering temperature		Tsol	260	℃

*1 Pulse width ≤100 μs, Duty ratio -0.001

*2 40 to 60%RH, AC for 1 minute

*3 For 10 seconds

■ Electro-optical Characteristics

(Ta = 25℃)

Parameter			Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage		V _F	I _F =20mA		1.2	1.4	V
	Peak forward voltage		V _{FM}	I _{FM} =0.5A	—	—	3.0	v
	Reverse current		I _R	V _R =4V			10	μ A
	Terminal capacitance		C _t	V=0, f=1kHz	—	30	250	pF
Output	Collector dark current		I _{CEO}	V _{CE} =20V			10 ⁻⁷	A
Transfer charac teristics	‘Current transfer ratio		CTR	I _F =5mA, V _{CE} =5V	50	—	600	%
	Collector-emitter saturation voltage		V _{CE(sat)}	I _F =20mA, I _C =1mA	—	0.1	0.2	V
	Isolation resistance		R _{ISO}	DC500V, 40 to 60%RH	5 × 10 ¹⁰	10 ¹¹	—	Ω
	Floating capacitance		C _f	V=0, f=1MHz	—	0.6	1.0	pF
	‘Cut -off frequency		f _c	V _{CE} =5V, I _C =2mA, R _L =100Ω, -3dB	—	80	—	kHz
Response time		Rise time	t _r	V _{CE} =2V, I _C =2mA, R _L =100Ω	—	4	18	μ s
		Fall time	t _f		—	3	18	μ s

*4 Classification table of current transfer ratio is shown below.

Model No.	Rank mark	CTR (%)
PC817A	A	80 to 160
PC817B	B	130 to 260
PC817C	c	200 to 400
PC817D	r)	300 to 600
PC8*7A8	A or H	80 to 260
PC8*7BC	B or C	130 to 400
PC8*7CD	C or D	200 to 600
PC8*7AC	A, B or C	80 to 400
PC8*7BD	B, C or D	130 to 600
PC8*7AD	A, B, C or D	80 to 600
PC8*7	A, B, C, D or No mark	50 to 600

* : 1 or 2 or 3 or 4

Fig. 1 Forward Current vs. Ambient Temperature

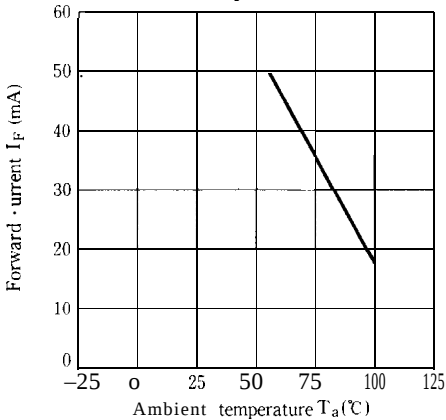


Fig. 2 Collector Power Dissipation VS. Ambient Temperature

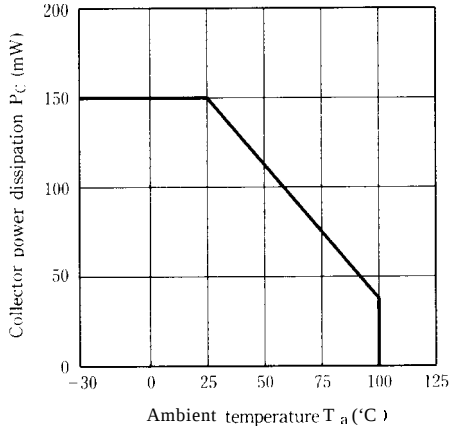


Fig. 4 Current Transfer Ratio vs. Forward Current

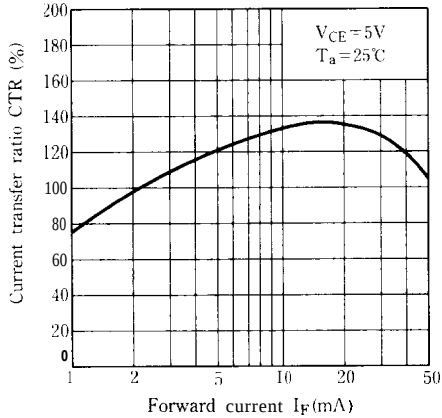


Fig. 6 Collector Current vs. Collector-emitter Voltage

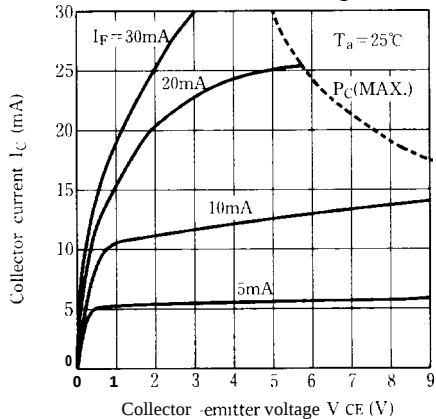


Fig. 3 Peak Forward Current vs. Duty Ratio

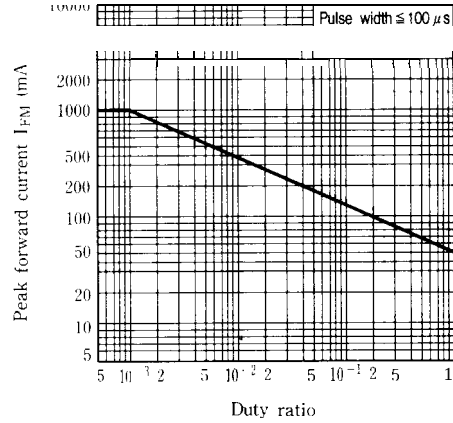


Fig. 5 Forward Current vs. Forward Voltage

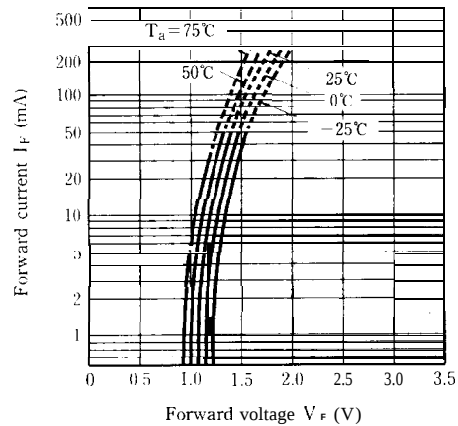


Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature

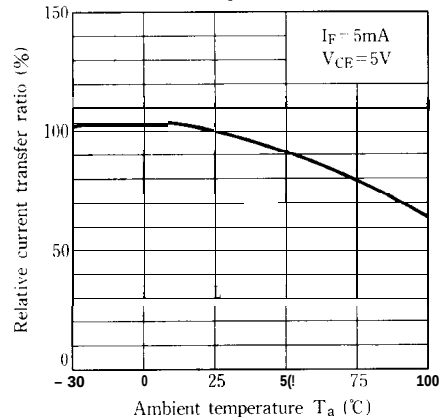
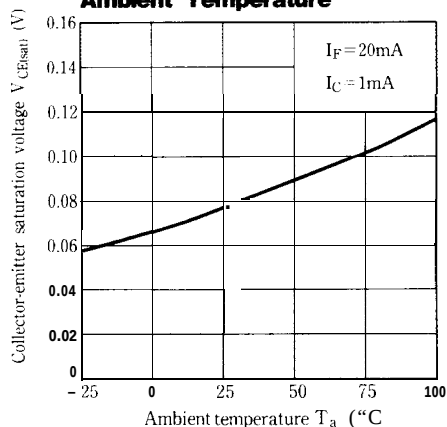
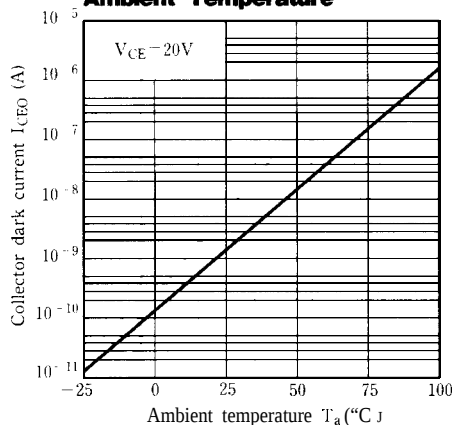
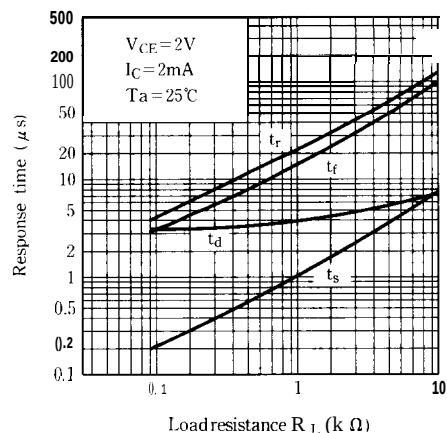
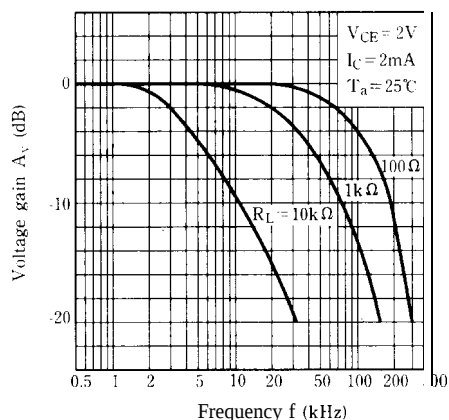
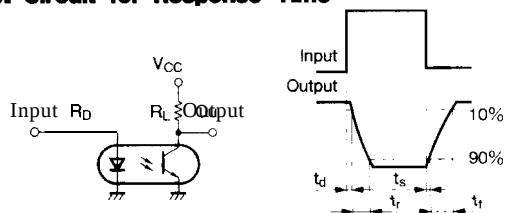
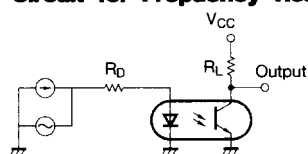


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature**Fig. 9 Collector Dark Current vs. Ambient Temperature****Fig.10 Response Time vs. Load Resistance****Fig.11 Frequency Response****Test Circuit for Response Time****Test Circuit for Frequency Response****Fig.12 Collector-emitter Saturation Voltage vs. Forward Current**